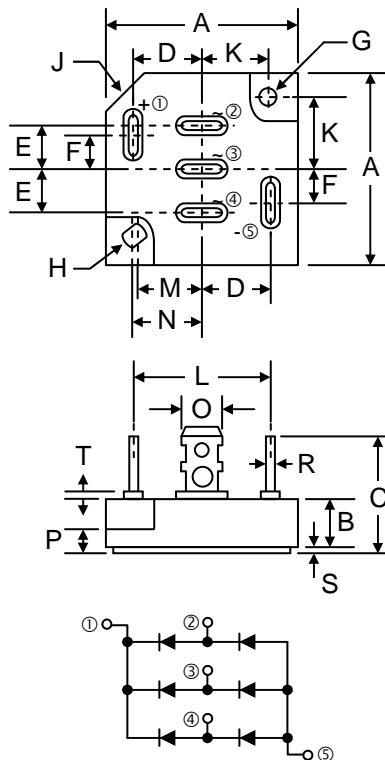


Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards
- Plastic Material has UL Recognition
Flammability Classification Rating 94V-O

Mechanical Data

- Case: Epoxy Case
Mounted in the Bridge Encapsulation
- Terminals: Plated Faston Lugs Solderable
per MIL-STD-202, Method 208
- Polarity: See Diagram Below
- Weight: 37 grams (approx.)
- Mounting Position: Bolt Down on Heatsink
With Silicone Thermal Compound Between
Module and Mounting Surface for Maximum
Heat Transfer Efficiency
- Mounting Torque: 0.8 N.m Max.
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version,
Add “-LF” Suffix to Part Number, See Page 4**



SVT		
Dim	Min	Max
A	—	36.0
B	9.8	10.4
C	—	29.0
D	13.1	14.1
E	8.5	9.5
F	6.5	7.5
G	3.5 Ø Typical	
H	R 1.75 Typical	
J	3.7 x 45°	
K	—	12.8
L	26.2	28.2
M	—	12.5
N	—	13.1
O	6.2	6.5
P	5.5	6.5
R	0.7	0.9
S	1.0	1.8
T	1.4	1.6
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	S50VT60	S50VT80	S50VT160	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	800	1600	V
RMS Reverse Voltage	V _{R(RMS)}	420	560	1120	V
Average Rectified Output Current @T _C = 55°C	I _O	50			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	500			A
Forward Voltage per diode @I _F = 25A	V _{FM}	1.1			V
Peak Reverse Current At Rated DC Blocking Voltage	I _{RM}	10			µA
I ² t Rating for Fusing per diode (1ms < t < 10ms)	I ² t	800			A ² s
Thermal Resistance Junction to Case (Note 1)	R _{θJC}	0.7			°C/W
RMS Isolation Voltage from Case to Leads	V _{ISO}	2000			V
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150			°C

Note: 1. Mounted on 229 x 152 x 127mm Al. finned plate.

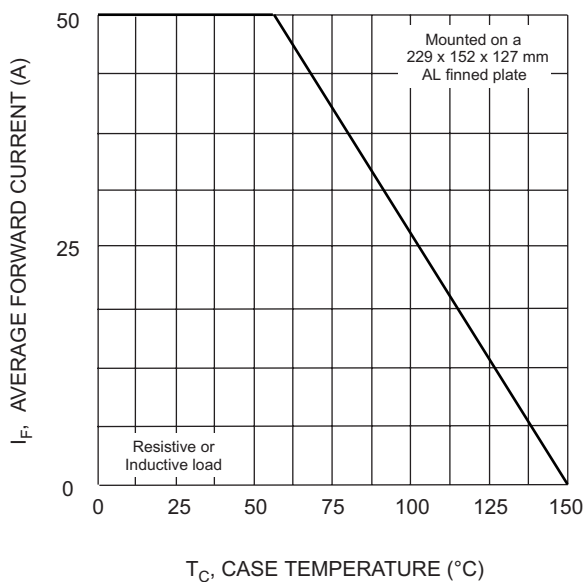


Fig. 1 Forward Current Derating Curve

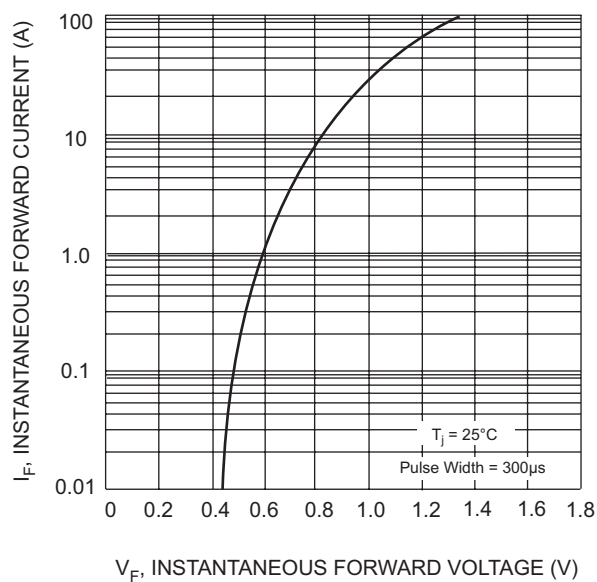


Fig. 2 Typical Forward Characteristics (per element)

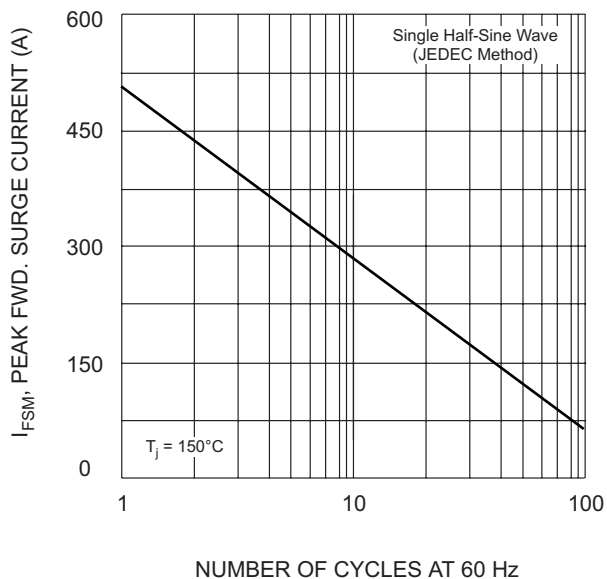


Fig. 3 Max Non-Repetitive Surge Current

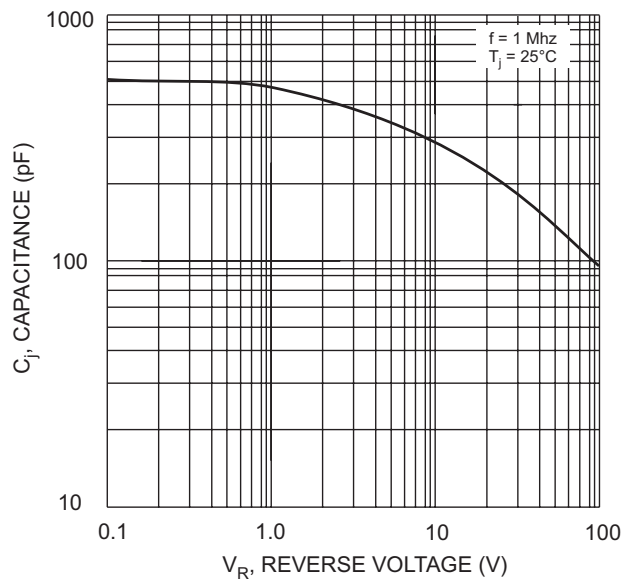


Fig. 4 Typical Junction Capacitance (per element)

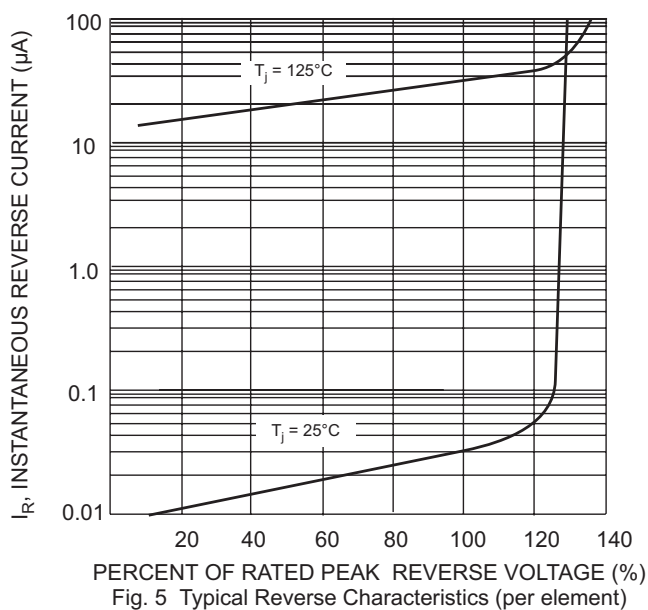
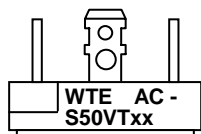


Fig. 5 Typical Reverse Characteristics (per element)

MARKING INFORMATION



WTE = Manufacturer's Logo
S50VTxx = Device Number
xx = 60, 80 or 160
Polarity = As Marked on Body

PACKAGING INFORMATION

BULK

Inner Box Size L x W x H (mm)	Quantity (PCS)	Carton Size L x W x H (mm)	Quantity (PCS)	Approx. Gross Weight (KG)
195 x 195 x 40	25	405 x 205 x 240	250	12.0

Note: 1. Paper box, white or brown color.

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
S50VT60	Bridge Module	25 Units/Box
S50VT80	Bridge Module	25 Units/Box
S50VT160	Bridge Module	25 Units/Box

1. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
2. **To order Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, S50VT60-LF.**

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WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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